Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:

Ceramic

Overall Length:

0.785 inches

Terminal Length:

0.120 inches

Overall Height:

0.200 inches

Overall Width:

0.325 inches

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-116

Electrode Internally-electrically Connected To Case:

Collector

Component Name And Quantity:

4 transistor

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

40.0 collector to base voltage, dc all transistor and 15.0 collector to emitter voltage, dc all transistor and 4.5 breakdown voltage,

emitter-to-base, collector open all transistor

Current Rating Per Characteristic:

500.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

3.5 watts small-signal input power, common-collector preset all transistor

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

14 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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